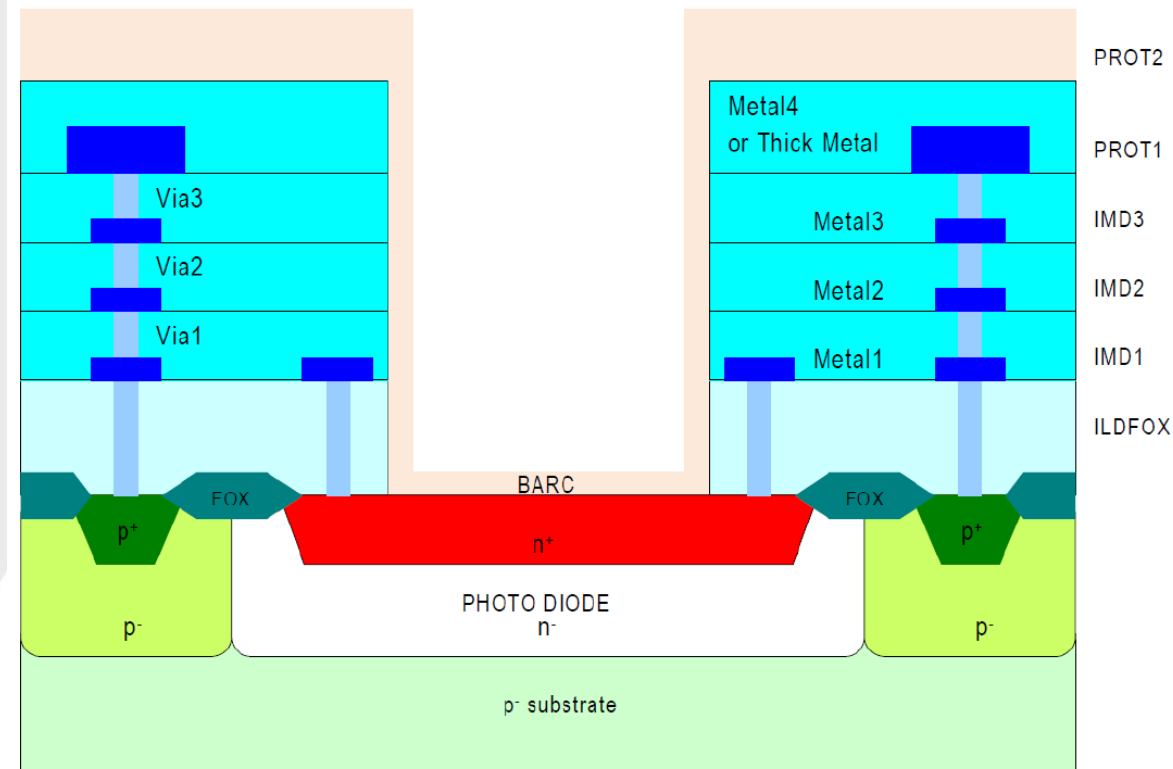


CMOS-Opto 0.35 μ m with Bottom Anti-Reflective Coating (BARC) (C35B40A)

- Bottom Anti-Reflective Coating allows better sensitivity than ARC.
- P-Epi wafers for lowering current leakage in the diode (lower dark current).



Cross-section of a photo-diode (BARC process option)

- Available from CMP at any of the 4 MPW runs in 2016.
- Contact CMP for pricing.